INTEGRATED CIRCUITS

DATA SHEET

LM139/239/239A/339/339A/ LM2901/MC3302

Quad voltage comparator

Product data Supersedes data of 2001 Aug 03 File under Integrated Circuits, IC11 Handbook 2002 Jan 22





Quad voltage comparator

LM139/239/239A/339/339A/ LM2901/MC3302

DESCRIPTION

The LM139 series consists of four independent precision voltage comparators, with an offset voltage specification as low as 2.0 mV max for each comparator, which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage. These comparators also have a unique characteristic in that the input common-mode voltage range includes ground, even though they are operated from a single power supply voltage.

The LM139 series was designed to directly interface with TTL and CMOS. When operated from both plus and minus power supplies, the LM139 series will directly interface with MOS logic where their low power drain is a distinct advantage over standard comparators.

FEATURES

- Wide single supply voltage range 2.0 V_{DC} to 36 V_{DC} or dual supplies ±1.0 V_{DC} to ±18 V_{DC}
- Very low supply current drain (0.8 mA) independent of supply voltage (1.0 mW/comparator at 5.0 V_{DC})
- Low input biasing current 25 nA
- Low input offset current ±5 nA and offset voltage
- Input common-mode voltage range includes ground
- Differential input voltage range equal to the power supply voltage
- Low output 250 mV at 4 mA saturation voltage
- Output voltage compatible with TTL, DTL, ECL, MOS and CMOS logic systems

APPLICATIONS

- A/D converters
- Wide range VCO
- MOS clock generator
- High voltage logic gate
- Multivibrators

PIN CONFIGURATION

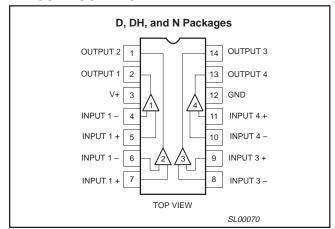


Figure 1. Pin Configuration

EQUIVALENT CIRCUIT

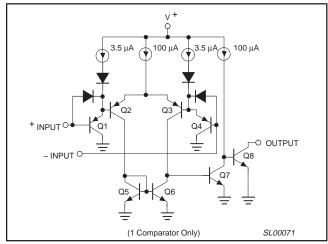


Figure 2. Equivalent Circuit

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
14-Pin Plastic Dual In-Line Package (DIP)	−55 °C to +125 °C	LM139N	SOT27-1
14-Pin Plastic Small Outline (SO) Package	−25 °C to +85 °C	LM239D	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	−25 °C to +85 °C	LM239N	SOT27-1
14-Pin Plastic Dual In-Line Package (DIP)	−25 °C to +85 °C	LM239AN	SOT27-1
14-Pin Plastic Small Outline (SO) Package	-40 °C to +125 °C	LM2901D	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	-40 °C to +125 °C	LM2901N	SOT27-1
14-Pin Plastic Small Outline (SO) Package	0 °C to +70 °C	LM339AD	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	0 °C to +70 °C	LM339AN	SOT27-1
14-Pin Plastic Small Outline (SO) Package	0 °C to +70 °C	LM339D	SOT108-1
14-Pin Plastic Thin Shrink Small Outline Package (TSSOP)	0 °C to +70 °C	LM339DH	SOT402-1
14-Pin Plastic Dual In-Line Package (DIP)	0 °C to +70 °C	LM339N	SOT27-1
14-Pin Plastic Small Outline (SO) Package	-40 °C to +85 °C	MC3302D	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	−40 °C to +85 °C	MC3302N	SOT27-1

Quad voltage comparator

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	V _{CC} supply voltage	36 or ±18	V _{DC}
V_{DIFF}	Differential input voltage	36	V _{DC}
V _{IN}	Input voltage	-0.3 to +36	V _{DC}
P _D	Maximum power dissipation, T _{amb} = 25 °C (still–air) ¹ N package D package LM339DH package	1420 1040 762	mW mW mW
	Output short-circuit to ground ²	Continuous	
I _{IN}	Input current (V _{IN} < -0.3 V _{DC}) ³	50	mA
T _{amb}	Operating temperature range LM139 LM239/239A LM339/339A LM2901 MC3302	-55 to +125 -25 to +85 0 to +70 -40 to +125 -40 to +85	°C °C °C °C
T _{stg}	Storage temperature range	-65 to +150	°C
T _{sld}	Lead soldering temperature (10 sec max)	230	°C

NOTES:

1. Derate above 25 °C, at the following rates:

N Package at 11.4 mW/°C

D Package at 8.3 mW/°C

DH Package at 6.1 mW/°C

2. Short circuits from the output to V+ can cause excessive heating and eventual destruction. The maximum output current is approximately 20 mA independent of the magnitude of V+.

3. This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector–base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the comparators to go to the V+ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will reestablish when the input voltage, which was negative, again returns to a value greater than –0.3 V_{DC}.

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Quad voltage comparator

DC AND AC ELECTRICAL CHARACTERISTICS

 $V+ = 5 \ V_{DC}; \ LM139: -55 \ ^{\circ}C \le T_{amb} \le +125 \ ^{\circ}C; \ LM239/239A: -25 \ ^{\circ}C \le T_{amb} \le +85 \ ^{\circ}C; \ LM339/339A: 0 \ ^{\circ}C \le T_{amb} \le +70 \ ^{\circ}C; \ LM2901: -40 \ ^{\circ}C \le T_{amb} \le +125 \ ^{\circ}C; \ MC3302: -40 \ ^{\circ}C \le T_{amb} \le +85 \ ^{\circ}C, \ unless \ otherwise \ specified.$

OVMDOL	DADAMETED	TEGT CONDITIONS	L	LINIT		
SYMBOL	PARAMETER	TEST CONDITIONS	Min	Тур	Max	UNIT
V	Input offset voltage ²	T _{amb} = 25 °C		±1.0	±2.0	mV
Vos	input onset voltage-	Over temp.			±4.0	mV
V	Input common-mode voltage	T _{amb} = 25 °C	0		V+ -1.5	V
V _{CM}	range ³	Over temp.	0		V+ -2.0	V
V_{IDR}	Differential input voltage ¹	Keep all $V_{IN} \ge 0 V_{DC}$ (or V- if needed)			V+	V
I _{BIAS}	Input bias current ⁴		25	250 400	nA nA	
I _{OS}	Input offset current	$I_{IN(+)} - I_{IN(-)}$ $T_{amb} = 25 ^{\circ}C$ Over temp.		±5.0	±50 ±150	nA nA
I _{OL}	Output sink current	$V_{IN(-)} \ge 1 \ V_{DC}; \ V_{IN}(+) = 0; \ V_O \le 1.5 \ V_{DC};$ $T_{amb} = 25 \ ^{\circ}C$	6.0	16		mA
	Output leakage current	$V_{IN(+)} \ge 1 \ V_{DC}; \ V_{IN}(-) = 0$ $V_{O} = 5 \ V_{DC}; \ T_{amb} = 25 \ ^{\circ}C$ $V_{O} = 30 \ V_{DC}; \ over temp.$		0.1	1.0	nA μA
Icc	Supply current	$R_L = \infty$ on comparators; V+ = 30 V; $T_{amb} = 25 ^{\circ}\text{C}$		0.8	2.0	mA
A _V	Voltage gain	$R_L \ge 15 \text{ k}\Omega; V+ = 15 \text{ V}_{DC}$	50	200		V/mV
V _{OL}	$V_{IN(-)} \geq 1 \ V_{DC}; \ V_{IN(+)} = 0; \ I_{SINK} \leq 4 \ mA$ Saturation voltage $T_{amb} = 25 \ ^{\circ}C$ Over temp.			250	400 700	mV mV
t _{LSR}	Large-signal response time	V_{IN} = TTL logic swing; V_{REF} = 1.4 V_{DC} ; V_{RL} = 5 V_{DC} ; R_L = 5.1 $k\Omega$; T_{amb} = 25 °C		300		ns
t _R	Response time ⁵	$V_{RL} = 5 V_{DC}; R_{L} = 5.1 k\Omega; T_{amb} = 25 °C$		1.3		μs

See notes at the end of the Electrical Characteristics.

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LM139/239/239A/339/339A/ LM2901/MC3302

DC AND AC ELECTRICAL CHARACTERISTICS (continued)

 $V+ = 5 \ V_{DC}; \ LM139: -55 \ ^{\circ}C \le T_{amb} \le +125 \ ^{\circ}C; \ LM239/239A: -25 \ ^{\circ}C \le T_{amb} \le +85 \ ^{\circ}C; \ LM339/339A: 0 \ ^{\circ}C \le T_{amb} \le +70 \ ^{\circ}C; \ LM2901: -40 \ ^{\circ}C \le T_{amb} \le +125 \ ^{\circ}C; \ MC3302: -40 \ ^{\circ}C \le T_{amb} \le +85 \ ^{\circ}C, \ unless \ otherwise \ specified.$

OVMDOL	DADAMETER	TEST COMPLETIONS		LM13	9	-	LM239/3	39	UNIT
SYMBOL	PARAMETER	TEST CONDITIONS	Min	Тур	Max	Min	Тур	Max	UNII
V	Innut offeet veltege?	T _{amb} = 25 °C		±2.0	±5.0		±2.0	±5.0	mV
V _{OS}	Input offset voltage ²	Over temp.			±9.0			±9.0	mV
V	Input common-mode	T _{amb} = 25 °C	0		V+-1.5	0		V+-1.5	V
V _{CM}	voltage range ³	Over temp.	0		V+-2.0	0		V+-2.0	V
V _{IDR}	Differential input voltage ¹	Keep all $V_{IN} \ge 0 V_{DC}$ (or V– if needed)			V+			V+	V
I _{BIAS}	Input bias current ⁴	$I_{IN(+)}$ or $I_{IN(-)}$ with output in linear range T_{amb} = 25 °C Over temp.		25	100 300		25	250 400	nA nA
I _{OS}	Input offset current	I _{IN(+)} - I _{IN(-)} T _{amb} = 25 °C Over temp.		±3.0	±25 ±100		±5.0	±50 ±150	nA nA
I _{OL}	Output sink current	$V_{IN(-)} \ge 1 \ V_{DC}; \ V_{IN(+)} = 0;$ $V_{O} \le 1.5 \ V_{DC};$ $T_{amb} = 25 \ ^{\circ}C$	6.0	16		6.0	16		mA
	Output leakage current	$V_{IN(+)} \ge 1 \ V_{DC}; \ V_{IN(-)} = 0$ $V_{O} = 5 \ V_{DC}; \ T_{amb} = 25 \ ^{\circ}C$ $V_{O} = 30 \ V_{DC}; \ Over temp.$		0.1	1.0		0.1	1.0	nA μA
I _{CC}	Supply current	$R_L = \infty$ on comparators; V+ = 30 V; $T_{amb} = 25 ^{\circ}C$		0.8	2.0		0.8	2.0	mA
A _V	Voltage gain	$R_L \ge 15 \text{ k}\Omega; \text{ V+} = 15 \text{ V}_{DC}$	50	200		50	200		V/mV
V _{OL}	Saturation voltage	$\begin{split} V_{IN(-)} \geq 1 \ V_{DC}; \ V_{IN(+)} = 0; \ I_{SINK} \leq 4 \ mA \\ T_{amb} = 25 \ ^{\circ}C \\ Over \ temp. \end{split}$		250	400 700		250	400 700	mV mV
t _{LSR}	Large-signal response time	V_{IN} = TTL logic swing; V_{REF} = 1.4 V_{DC} ; V_{RL} = 5 V_{DC} ; R_L = 5.1 $k\Omega$; T_{amb} = 25 $^{\circ}C$		300			300		ns
t _R	Response time ⁵	$V_{RL} = 5 V_{DC}; R_L = 5.1 k\Omega;$ $T_{amb} = 25 °C$		1.3			1.3		μs

See notes on following page.

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LM139/239/239A/339/339A/ LM2901/MC3302

DC AND AC ELECTRICAL CHARACTERISTICS (continued)

 $V+ = 5 \ V_{DC}; LM139: -55 \ ^{\circ}C \le T_{amb} \le +125 \ ^{\circ}C; LM239/239A: -25 \ ^{\circ}C \le T_{amb} \le +85 \ ^{\circ}C; LM339/339A: 0 \ ^{\circ}C \le T_{amb} \le +70 \ ^{\circ}C; LM2901: -40 \ ^{\circ}C \le T_{amb} \le +125 \ ^{\circ}C; MC3302: -40 \ ^{\circ}C \le T_{amb} \le +85 \ ^{\circ}C, unless otherwise specified.$

OVMDOL	DADAMETED	TEST COMPLETIONS		LM290)1		MC330)2	UNIT
SYMBOL	PARAMETER	TEST CONDITIONS	Min	Тур	Max	Min	Тур	Max	UNII
.,	Leave offer to all and 2	T _{amb} = 25 °C		±2.0	±7.0		±3.0	±20	mV
Vos	Input offset voltage ²	Over temp.		±9	±15			±40	mV
\/	Input common-mode	T _{amb} = 25 °C	0		V+-1.5	0		V+-1.5	V
V_{CM}	voltage range ³	Over temp.	0		V+-2.0	0		V+-2.0	V
V _{IDR}	Differential input voltage ¹	Keep all $V_{IN} \ge 0 V_{DC}$ (or V– if needed)			V+			V+	V
I _{BIAS}	Input bias current ⁴	$I_{\text{IN(+)}}$ or $I_{\text{IN(-)}}$ with output in linear range $T_{\text{amb}} = 25 ^{\circ}\text{C}$ Over temp.		25 200	250 500		25	500 1000	nA nA
los	Input offset current	I _{IN(+)} - I _{IN(-)} T _{amb} = 25 °C Over temp.		±5 ±50	±50 ±200		±5	±100 ±300	nA nA
I _{OL}	Output sink current	$V_{IN(-)} \ge 1 \ V_{DC}; \ V_{IN(+)} = 0;$ $V_{O} \le 1.5 \ V_{DC}; \ T_{amb} = 25 \ ^{\circ}C$	6.0	16		6	16		mA
	Output leakage current	$V_{IN(+)} \ge 1 \ V_{DC}; \ V_{IN(-)} = 0$ $V_{O} = 5 \ V_{DC}; \ T_{amb} = 25 \ ^{\circ}C$ $V_{O} = 30 \ V_{DC}; \ Over temp.$		0.1	1.0		0.1	1.0	nA μA
		R _L = ∞ on all comparators,					0.8	1.8	mA
	Cupply gurrant	T _{amb} = 25 °C		0.8	2.0				
Icc	Supply current	R _L = ∞ on all comparators, V+ = 30 V		1.0	2.5				mA
A _V	Voltage gain	$R_L \ge 15 \text{ k}\Omega; V+ = 15 V_{DC}$	25	100		2	100		V/mV
V _{OL}	Saturation voltage	$V_{IN(-)} \ge 1 \ V_{DC}; \ V_{IN(+)} = 0; \ I_{SINK} \le 4mA$ $T_{amb} = 25 \ ^{\circ}C$ Over temp.		400	400 700		150	400 700	mV mV
t _{LSR}	Large-signal response time	V_{IN} = TTL logic swing; V_{REF} = 1.4 V_{DC} ; V_{RL} = 5 V_{DC} ; V_{RL} = 5.1 V_{RC} ; V_{RMD} = 25 V_{RMD}		300			300		ns
t _R	Response time ⁵	$V_{RL} = 5 V_{DC}; R_L = 5.1 kΩ;$ $T_{amb} = 25 °C$		1.3			1.3		μs

NOTES:

- Positive excursions of input voltage may exceed the power supply level by 17 V. As long as the other voltage remains within the common-mode range, the comparator will provide a proper output state. The low input voltage state must not be less than -0.3 V_{DC} (or 0.3 V_{DC} below the magnitude of the negative power supply, if used).
- 2. At output switch point, $V_O \approx 1.4 \ V_{DC}$, $R_S = 0 \ \Omega$ with V+ from 5 V_{DC} to 30 V_{DC} ; and over the full input common-mode range (0 V_{DC} to V+ $-1.5 \ V_{DC}$). Inputs of unused comparators should be grounded.
- The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common-mode voltage range is V+ 1.5 V, but either or both inputs can go to 30 V_{DC} without damage.
 The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of
- 4. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the reference or input lines.
- 5. The response time specified is for a 100 mV input step with a 5 mV overdrive. For larger overdrive signals, 300 ns can be obtained (see Figure 4, Typical performance characteristics).

EQUIVALENT CIRCUIT

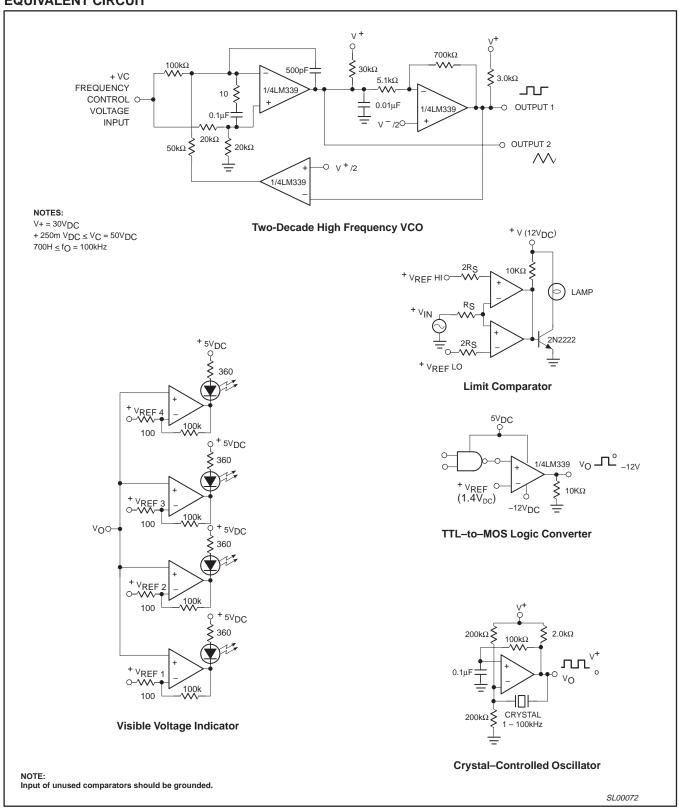


Figure 3. Equivalent circuit.

TYPICAL PERFORMANCE CHARACTERISTICS

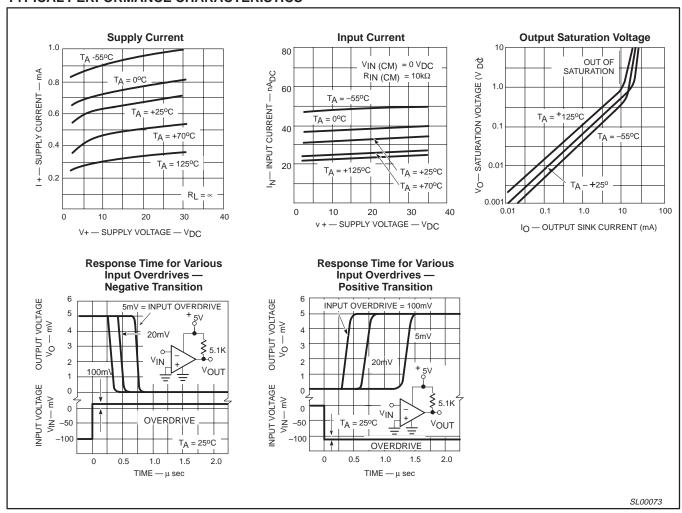
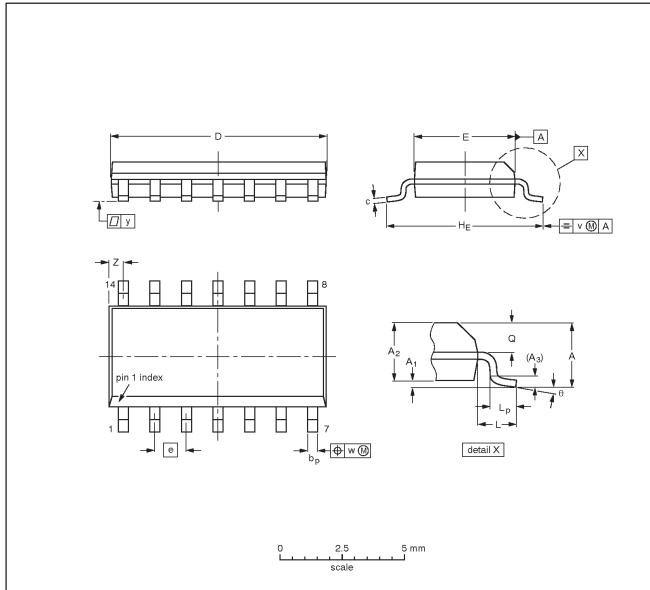


Figure 4. Typical performance characteristics.

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.35 0.34	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	O°

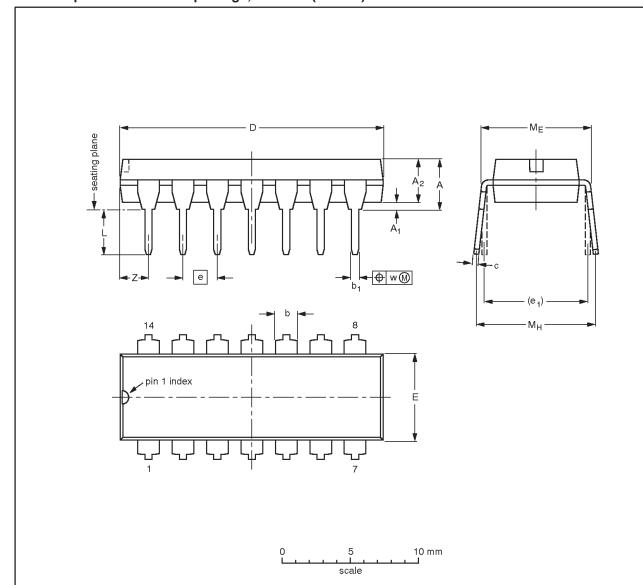
Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT108-1	076E06	MS-012			97-05-22 99-12-27	

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E (1)	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

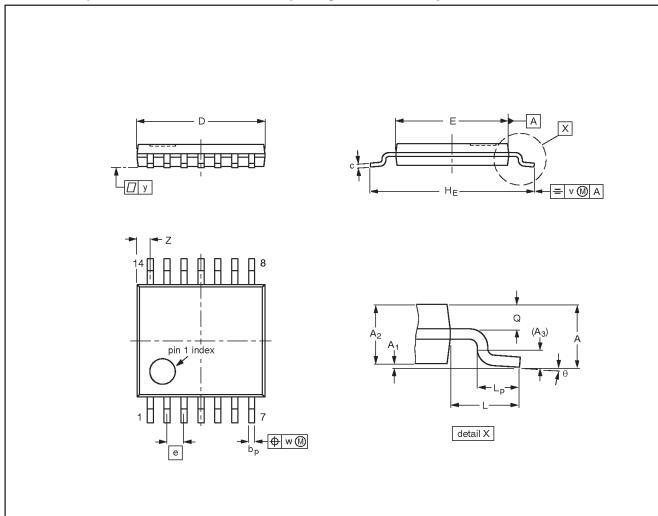
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

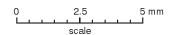
OUTLINE		REFEF	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1330E DATE
SOT27-1	050G04	MO-001	SC-501-14		95-03-11 99-12-27

Quad voltage comparator

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1





DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1330E DATE
SOT402-1		MO-153			-95-04-04 99-12-27

Quad voltage comparator

LM139/239/239A/339/339A/ LM2901/MC3302

Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

^[1] Please consult the most recently issued data sheet before initiating or completing a design.

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Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

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